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**\*BIBDATASHEET\***

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**CONFIRMATION NO. 2476**

SERIAL NUMBER 10/647,714	FILING DATE 08/25/2003 RULE	CLASS 438	GROUP ART UNIT 2818	ATTORNEY DOCKET NO. SETI-0002DIV
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**APPLICANTS**

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1714  
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This application is a DIV of 09/966,559 09/27/2001 PAT 6,690,042  
 which claims benefit of 60/235,563 09/27/2000

None *R***\*\* FOREIGN APPLICATIONS \*\*\*\*\*****IF REQUIRED, FOREIGN FILING LICENSE GRANTED \*\* SMALL ENTITY \*\***

\*\* 11/18/2003

Foreign Priority claimed	yes <input checked="" type="checkbox"/> no <input type="checkbox"/>	STATE OR COUNTRY	SHEETS	TOTAL	INDEPENDENT
35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> Met after Allowance <i>R</i>	SC	DRAWING 7	CLAIMS 20	CLAIMS 3
Verified and Acknowledged	Examiner's Signature <i>R</i>	Initials			

**ADDRESS**

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**TITLE**

Metal oxide semiconductor heterostructure field effect transistor

FILING FEE	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time )
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